

**1-Line Low Capacitance Bi-directional TVS Diode**
**Features**

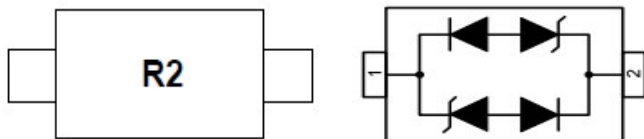
- 350W peak pulse power (8/20us)
- Ultra low capacitance : 1.5pF typical
- Ultra low leakage : nA level
- Low operating voltage : 12V
- Low clamping voltage
- Complies with following standards :
  - IEC 61000-4-2(ESD) immunity test  
Air discharge :  $\pm 30\text{kV}$ , Contact discharge :  $\pm 30\text{kV}$
  - IEC61000-4-4 (EFT) 40A (5/50ns)
  - IEC61000-4-5 (Lightning) 14A (8/20us)
- RoHS Compliant

**Mechanical Data**

- Package : SOD-323
- Case Material : "Green" Molding Compound.
- Lead Finish : Matte Tin
- UL Flammability Classification Rating 94V-0
- Moisture Sensitivity : Level 3 per J-STD-020
- Terminal Connections : See Diagram Below
- Marking Information : See Below

**Applications**

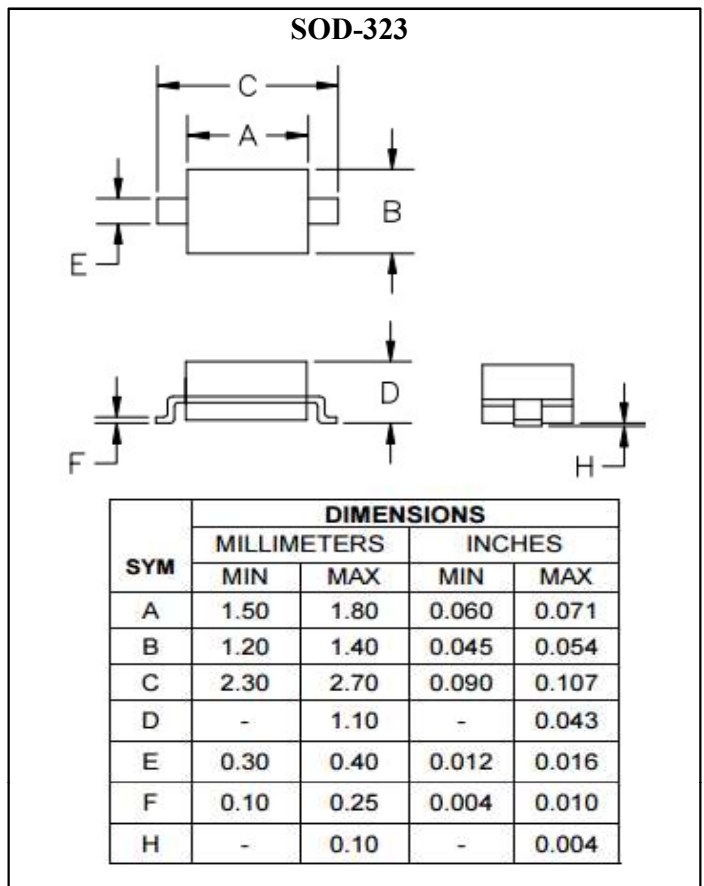
- USB Ports
- Smart Phones
- Wireless Systems
- Ethernet 10/100/1000 Base T

**Marking and Circuit Schematic**

**Absolute Maximum Ratings (Ta= 25°C unless otherwise specified)**

Parameter	Symbol	Value	Unit
Peak Pulse Power (8/20us)	P <sub>pk</sub>	500	W
Peak Pulse Current (8/20us)	I <sub>pp</sub>	12	A
ESD per IEC 61000-4-2 (Air)	V <sub>ESD</sub>	$\pm 30$	kV
ESD per IEC 61000-4-2 (Contact)		$\pm 30$	
Operating Junction Temperature Range	T <sub>J</sub>	-40 to +85	°C
Storage Temperature Range	T <sub>STG</sub>	-55 to +150	°C

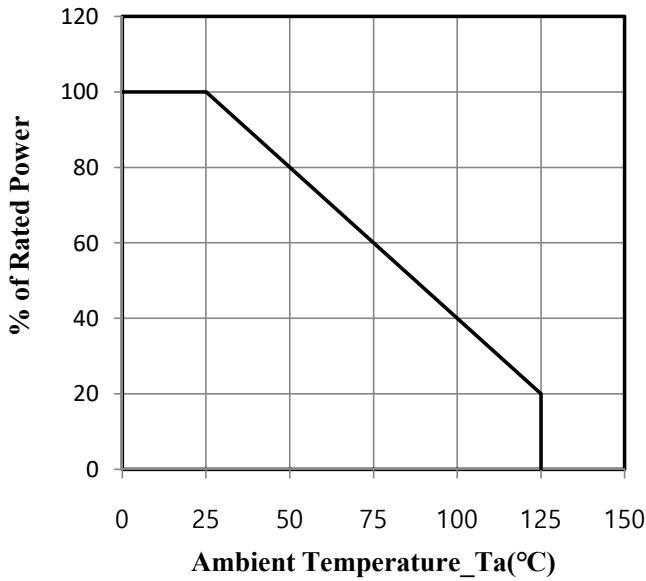
**Electrical Characteristics (Ta= 25°C unless otherwise specified)**

Characteristic	Symbol	Min.	Typ.	Max.	Unit	Test Condition
Reverse Working Voltage	V <sub>RWM</sub>	-	-	12	V	
Breakdown Voltage	V <sub>BR</sub>	13.3	-	17.8	V	I <sub>T</sub> = 1mA
Reverse Leakage Current	I <sub>R</sub>	-	-	0.2	uA	V <sub>RWM</sub> = 12V
Clamping Voltage	V <sub>C</sub>	-	-	18	V	I <sub>pp</sub> =1A(8×20us pulse)
Clamping Voltage	V <sub>C</sub>	-	-	35	V	I <sub>pp</sub> =14A(8×20us pulse)
Junction Capacitance	C <sub>J</sub>	-	1.5	-	pF	f=1MHz, V <sub>R</sub> =0V

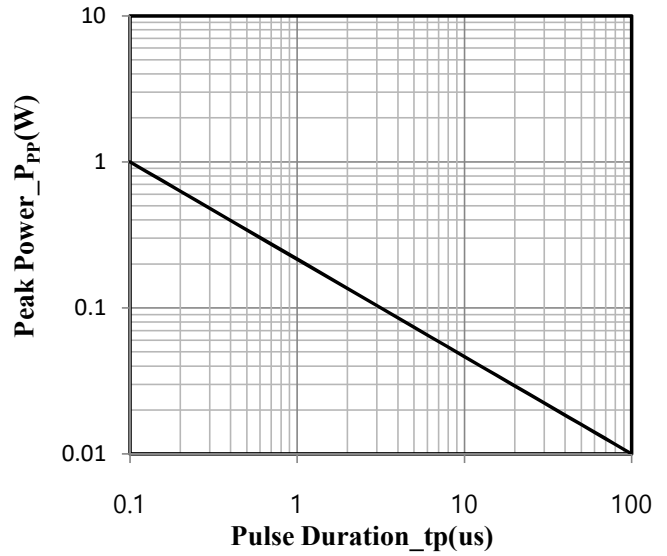


**Ratings and Characteristics Curves (Ta=25°C unless otherwise noted)**

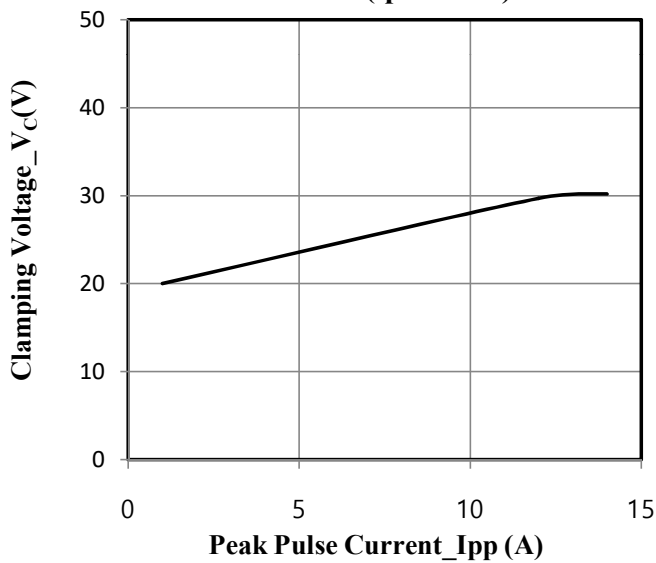
**Fig.1 Power Derating Curve**



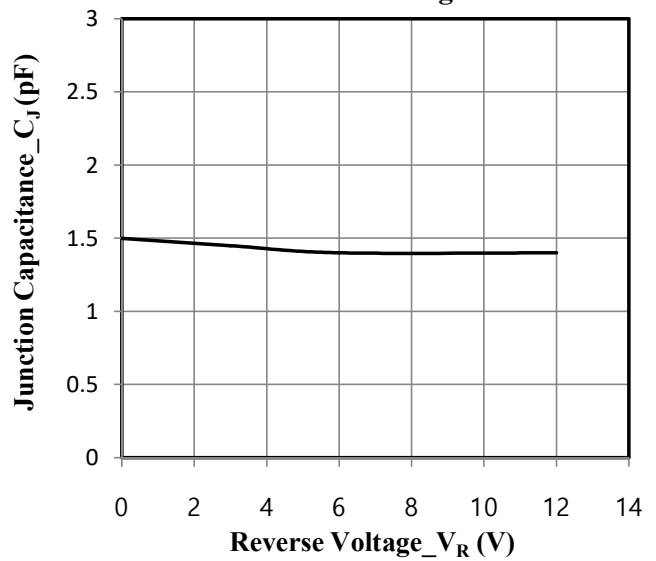
**Fig.2 Peak Pulse Power vs. Pulse Time**



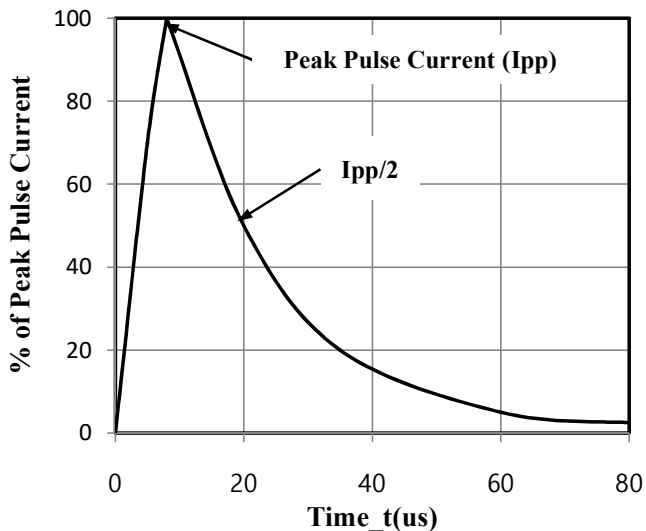
**Fig.3 Clamping Voltage vs. Peak Pulse Current (tp=8/20µs)**



**Fig.4 Junction Capacitance vs. Reverse Voltage**



**Fig.5 8 × 20µs Pulse Waveform**



**Fig. 6 ESD Clamping Voltage 8kV Contact per IEC61000-4-2**

